

# R4000F - R5000F HIGH VOLTAGE RECTIFIER DIODES

VOLTAGE RANGE: 4000 - 5000V CURRENT: 0.2 A

#### **Features**

- Low cost
- Low leakage
- Low forward voltage drop
- High current capability
- Easily cleaned with alcohol, Isopropanol
- and similar solvents

### **Mechanical Data**

Case: DO-15, Molded Plastic

Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208

Polarity: Cathode Band

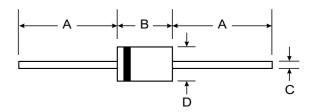
Weight: 0.40 grams (approx.)

Mounting Position: Any

Marking: Type Number







DO-15				
Dim	Min	Max		
Α	25.40	_		
В	5.50	7.62		
С	0.686	0.889		
D	2.60	3.60		
All Dimensions in mm				

## Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

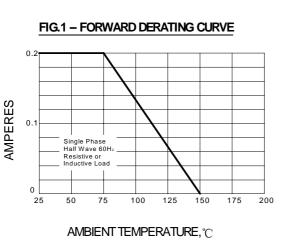
Characteristic	Symbol	R4000F	R5000F	Unit
Maximum recurrent peak reverse voltage	$V_{RRM}$	4000	5000	V
Maximum RMS voltage	V <sub>RMS</sub>	2800	3500	V
Maximum DC blocking voltage	$V_{DC}$	4000	5000	V
Maximum average forw ard rectified current 9.5mm lead length, @T <sub>A</sub> =75℃	I <sub>F(AV)</sub>	0.2		А
Peak forw ard surge current  8.3ms single half-sine-w ave superimposed on rated load @T <sub>J</sub> =125℃	I <sub>FSM</sub>	30	0.0	A
Maximum instantaneous forward voltage  @ 0.2A	V <sub>F</sub>	6	5.5	V
Maximum reverse current @T <sub>A</sub> =25°℃		5	.0	
at rated DC blocking voltage @T <sub>A</sub> =100℃	l <sub>R</sub>	100.0		μA
Maximum reverse recovery time (Note1)	t <sub>rr</sub>	500		ns
Typical junction capacitance (Note2)	CJ	15		pF
Operating junction temperature range	TJ	- 55	- + 150	°C
Storage temperature range	T <sub>STG</sub>	- 55	- + 150	$^{\circ}$

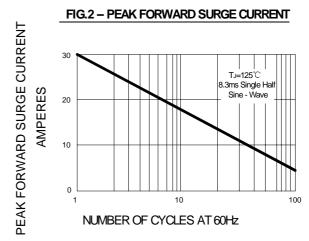
NOTE: 1. Measured with  $I_e$ =0.5A,  $I_g$ =1A,  $I_{rr}$ =0.25A.

2. Measured at  $\rm 1.0MH_{Z}$  and applied reverse voltage of 4.0V DC.

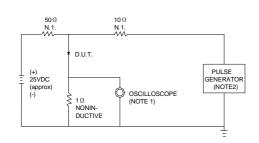


AVERAGE FORWARD RECTIFIED CURRENT

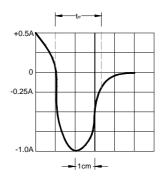




#### FIG.3 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES:1.RISETIME=7ns MAX.INPUT IMPEDANCE=1M $_{\Omega}$ . 22pF. 2.RISETIME=10ns MAX.SOURCE IMPEDANCE=50  $_{\Omega}$ .



SET TIME BASE FOR 50/100 ns/cm